

**isc Silicon NPN Power Transistor**

**BUV42A**

**DESCRIPTION**

- Low Collector Saturation Voltage-  
:  $V_{CE(sat)} = 0.9V(\text{Max.}) @ I_C = 4A$
- High Switching Speed

**APPLICATIONS**

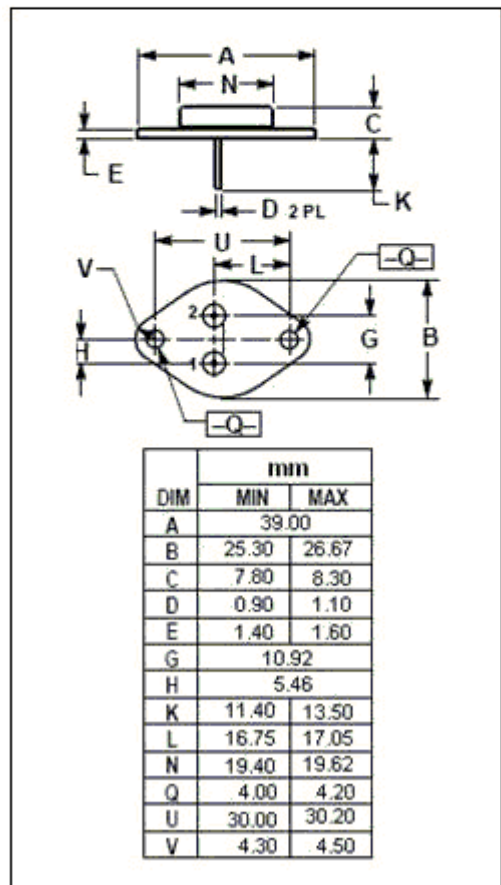
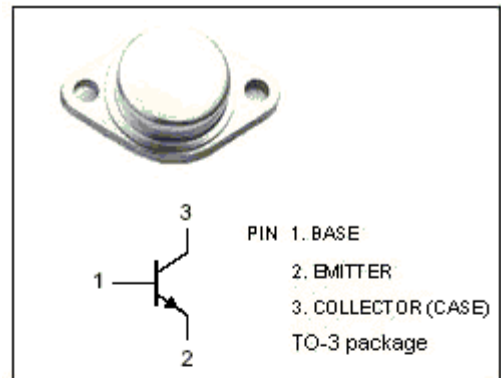
- Designed for high current, high speed, high power applications.

**Absolute maximum ratings(Ta=25°C)**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CEV}$	Collector-Emittor Voltage $V_{BE} = -1.5V$	400	V
$V_{CEO}$	Collector-Emittor Voltage	300	V
$V_{EBO}$	Emittor-Base Voltage	7	V
$I_C$	Collector Current-Continuous	12	A
$I_{CM}$	Collector Current-Peak	18	A
$I_B$	Base Current-Continuous	2.5	A
$I_{BM}$	Base Current- Peak	4	A
$P_C$	Collector Power Dissipation @ $T_C = 25^\circ C$	120	W
$T_j$	Junction Temperature	200	°C
$T_{stg}$	Storage Temperature Range	-65~200	°C

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
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$R_{th\ j-c}$	Thermal Resistance,Junction to Case	1.46	°C/W
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## ELECTRICAL CHARACTERISTICS

T<sub>C</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CE0(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 0.2A; I <sub>B</sub> = 0; L= 25mH	300			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 50mA; I <sub>C</sub> = 0	7			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 4A; I <sub>B</sub> = 0.4A			0.9	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 4A; I <sub>B</sub> = 0.4A			1.3	V
I <sub>CER</sub>	Collector Cutoff Current	V <sub>CE</sub> = 400V; R <sub>BE</sub> = 10Ω V <sub>CE</sub> = 400V; R <sub>BE</sub> = 10Ω ; T <sub>C</sub> =100°C			0.5 2.5	mA
I <sub>CEV</sub>	Collector Cutoff Current	V <sub>CE</sub> = 400V; V <sub>BE</sub> = -1.5V V <sub>CE</sub> = 400V; V <sub>BE</sub> = -1.5V; T <sub>C</sub> =100°C			0.5 2.0	mA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			1.0	mA